## NSN 5961-01-340-0686

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View Online at https://aerobasegroup.com/nsn/5961-01-340-0686 **Inclosure Material:** Metal **Overall Length:** 0.900 inches **Overall Height:** 0.285 inches **Overall Width:** 0.650 inches **End Application:** Radar set an/sps-40d **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Emitter **Component Name And Quantity:** 2 transistor **Mounting Method:** Slot **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open all transistor and 25.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 3.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 22.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 9.0 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold

N/a

**Terminal Type And Quantity:** 

1 case and 4 ribbon

**Unit Of Measure:** 

Shelf Life:

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Demilitarization:

No

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